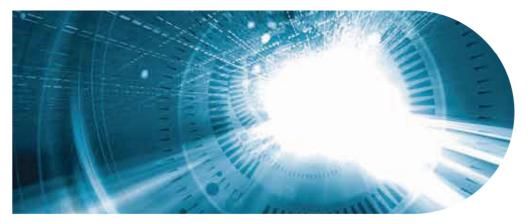
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Transmission Laser

Modules

KeyFeatures

InGaAsP monolithically integrated DFB laser and modulator in-house chip

Low drive voltage (≤ 2Vpp)

Very low dispersion penalty up to 40 km for 10.7Gbit/s operation (up to 800ps/nm)

XMD MSA compliant

FPC for electrical connections

Low TEC power $\leq 1W$

RoHs compliant

Applications

STM-64 (Short-Haul) and OC-192 (Intermediate-Reach) XFP transceiver

For moreInfo

Please contact us at: North America: **514.748.4848**

ea: **514.748.4848 888.922.1044**

Europe & Asia: +33 (0) 1 69 80 58 33 or via e-mail at sales@3spgroup.com

1925 LMM

10 Gb/s Electro-Absorptive Integrated Laser Modulator Optical Sub-Assembly 800 ps/nm – TDM – LC receptacle

This 1925 LMM contains a 3S PHOTONICS DFB laser with monolithically integrated electro-absorption modulator.

The modulation voltage is applied to the modulator section while the DFB laser operates CW. Without the complexity of LiNbO3 external modulators, the 1925 LMM is dedicated to STM64 / OC-192 bit rate with reduced size and cost. This device allows 10 Gbit/s data transmission with an extinction ratio higher than 10dB and less than 2V modulation voltage.

The 1925 LMM is optimized for up to 10.7Gbit/s TDM transmission systems supporting dispersion up to 800 ps/nm.





10 Gb/s Electro-Absorptive Integrated Laser Modulator Optical Sub-Assembly – 800 ps/nm – TDM – LC receptacle





OPTICAL CHARACTERISTICS

Table 1

Parameters	Symb	Test conditions	Min	Max	Units
Operating case temperature	Tc	Standard case temperature	-5	75	∞
Laser threshold current	lth	V _{ON} op	5	35	mA
Laser operating current	lop	V _{ON} op BOL	70	100	mA
Laser chip temperature	Twave		35		℃
ON stage voltage	V _{ON}		-1	0	V
Modulator drive voltage	V_{mod}	Note 1		2.5	Vpp
Average optical output power	P _{AVG}	lop, DER , λc, notes 1, 2	-1	+2	dBm
Center wavelength range	λc	Twave	1529	1561	nm
Dynamic Extinction Ratio	DER	lop , notes 1, 2	9		dB
Dispersion penalty	ΔS	DER, notes 1, 2		2	dB
Side Mode Suppression Ratio	SMSR	note 1	35		dB
Monitor diode current	lm	lop , V=-5V	50	1000	μΑ
Dark current	ld			0.1	μΑ
TEC current	It	D VDM I 4T 4000		0.8	Α
TEC voltage	Vt	P_{AVG} op, VBM op, lop, $\Delta T = 40 ^{\circ}\text{C}$		1.7	V
TEC power	Wp	P _{AVG} op, VBM op, lop, ΔT =40 °C		1.3	W
Tracking error	TE	@Ppeak	-0.5	+0.5	dB
Thermistor resistance	RTH	Ts=25℃	9.5	10.5	ΚΩ
Thermistor β coefficient	β	Ts=25℃	3800	4000	K

Note 1 : BER= 10-10, 10.7Gb/s, modulation, 231-1 PRBS, NRZ line code, driver OKI 4145KW

Note 2:800 ps/nm minimum dispersion @ 1550nm.

An PIN-TIA receiver with sensitivity better than –18 dBm BER 1E-10 in Back to Back is used.

ABSOLUTE MAXIMUM RATINGS

 Table 2

 Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameters	Min	Max.	Unit
Storage case temperature	-40	+85	℃
Laser Forward Current		150	mA
Laser Reverse Voltage		2	V
Laser Reverse Current		10	μΑ
Modulator Forward Voltage		1	V
Modulator Forward Current		100	mA
Modulator Reverse Voltage		5	V
Modulator Reverse Current		10	μΑ
Photodiode Forward Current		1	mA
Photodiode Reverse Voltage		20	V
TEC Voltage		2.6	V
TEC Current		1.3	Α
Flex pad soldering Temperature (5s)		290	℃
Flex pad allowed soldering rework		1	time
Flex torsion angle	-10	10	0
Flex (FPC) bending radius	2		mm

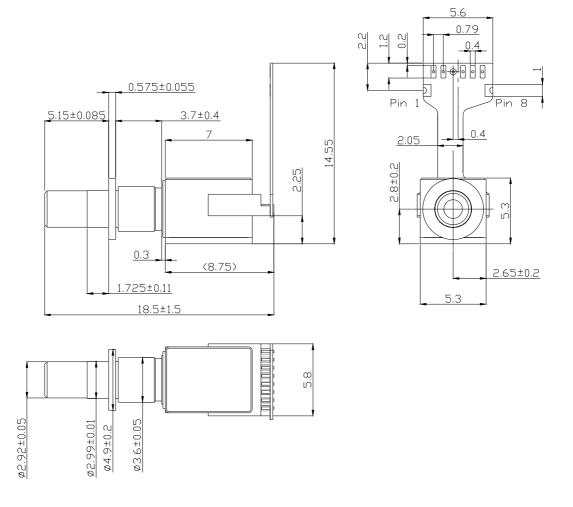
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10 Gb/s Electro-Absorptive Integrated Laser Modulator Optical Sub-Assembly – 800 ps/nm – TDM – LC receptacle



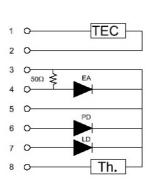


MECHANICAL DETAILS



PIN **OUT**

N°	Description		
1	TE Cooler Cathode		
2	TE Cooler Anode		
3	Floating signal ground		
4	Modulator Anode (bias-)		
5	Floating signal ground		
6	PD Anode (bias-)		
7	LD Anode (bias-)		
8	Thermistor		





10 Gb/s Electro-Absorptive Integrated Laser Modulator Optical Sub-Assembly – 800 ps/nm – TDM – LC receptacle





SHIPMENT PACKING

Each device is individually packed in an anti-static container and in such a manner as to prevent damage in transit.

The packing shall include the following information:

3S PHOTONICS logo

Product family name: 1925 LMM

Product code: 3CN number (see Ordering information section)

Serial number

Hazard warning label (ESD) Laser Safety Class Label

DELIVERABLE **DATA**

The following data shall be supplied with each device under EDF format:

Ith, Imon, It, Vt, Pt, If, Tlaser, Pave, DER, DS, Driver Modulation Voltage, Driver Offset Voltage, Driver Eye Crossing Voltage

LASER SAFETY INFORMATION

Take appropriate precautions to prevent undue exposure to naked eye.

This product is classified Class 1M Laser Product according to IEC-60825-1: edition2.

All versions are Class IIIB laser products per 21 CFR 1040-10 Laser. Safety requirements under accession number 0120546-00.



HANDLING

This product is sensitive to electrostatic discharge and should not be handled except at a static free workstation. Take precautions to prevent ESD; use wrist straps, grounded work surfaces and recognized anti-static techniques when handling the module.

Handle the PD module by its package only, never hold it by its receptacle.

Care should be taken to avoid supply transient and over voltage. Over voltage above the maximum specified in absolute maximum rating section may cause permanent damage to the device.





10 Gb/s Electro-Absorptive Integrated Laser Modulator Optical Sub-Assembly – 800 ps/nm – TDM – LC receptacle





ORDERING INFORMATION

1925 LMM LC receptacle – FPC

Application	Part number	Output Power	Case Temperature
800 ps/nm - TDM	3CN01633AS	[-1;+2] dBm	Commercial

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